

7. (Amended) The ceramic substrate according to claim 5,
wherein said ceramic substrate comprises nitride ceramic and said nitride ceramic
contains sulfur therein.

8. (Amended) The ceramic substrate according to claim 5,
wherein the content of said sulfur is in a range of 0.05 to 200 ppm.

9. (Amended) The ceramic substrate according to claim 5,
wherein said ceramic substrate contains oxygen.

10. (Amended) A ceramic heater,
wherein the ceramic substrate according to claim 5 is used.

11. (Amended) An electrostatic chuck,
wherein the ceramic substrate according to claim 5 is used.